

# ROITHNER LASERTECHNIK

A-1040 VIENNA, SCHOENBRUNNER STRASSE 7, AUSTRIA

TEL: +43 -1- 586 52 43-0 FAX: +43 -1- 586 52 43-44

office@roithner-laser.com www.roithner-laser.com

## RLT6650G TECHNICAL DATA



### High Power Visible Laserdiode

Structure: High Efficiency MOVCD Quantum Well Design

Lasing wavelength: 660 nm typ., multimode

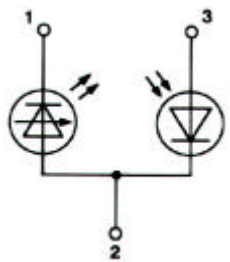
Output power: 50 mW

Package: 9 mm

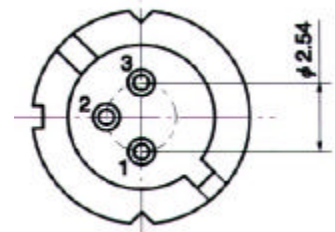


**NOTE!**  
LASERDIODE  
MUST BE COOLED!

#### PIN CONNECTION:



- 1) Laser diode cathode
- 2) Laser diode anode and photodiode cathode
- 3) Photodiode anode



#### Absolute Maximum Ratings (T<sub>c</sub>=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P <sub>o</sub>	55	mW
LD Reverse Voltage	V <sub>R(LD)</sub>	2	V
PD Reverse Voltage	V <sub>R(PD)</sub>	30	V
Operating Temperature	T <sub>C</sub>	-10 .. +40	°C
Storage Temperature	T <sub>STG</sub>	-40 .. +85	°C

#### Optical-Electrical Characteristics (T<sub>c</sub> = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Optical Output Power	P <sub>o</sub>	cw operation		50		mW
Threshold Current	I <sub>th</sub>	cw operation	70	85	120	mA
Operation Current	I <sub>op</sub>	P <sub>o</sub> = 50 mW	135	160	220	mA
Operation Voltage	V <sub>op</sub>	P <sub>o</sub> = 50 mW	2.0	2.1	2.2	V
Lasing Wavelength	λ <sub>p</sub>	P <sub>o</sub> = 50 mW	655	660	665	nm
Beam Divergence	θ <sub>//</sub>	P <sub>o</sub> = 50 mW	10	12	14	°
Beam Divergence	θ <sub>⊥</sub>	P <sub>o</sub> = 50 mW	20	25	30	°
Lasing Aperture	A	P <sub>o</sub> = 50 mW		10 x 1		μm <sup>2</sup>
Monitor Current	I <sub>m</sub>	P <sub>o</sub> = 50 mW	0.35	0.5	1.5	mA